

MBR2090CT-M3, MBR20100CT-M3

Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier



| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|----------------|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | |
| V _{RRM} | 90 V, 100 V | | | |
| I _{FSM} | 150 A | | | |
| V _F | 0.65 V | | | |
| T _J max. | 150 °C | | | |
| Package | TO-220AB | | | |
| Diode variation | Common cathode | | | |

FEATURES

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

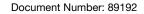
Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

| PARAMETER | | SYMBOL | MBR2090CT | MBR20100CT | UNIT |
|--|--------------|----------------------|---|------------|------|
| Max. repetitive peak reverse voltage | | V _{RRM} | 90 | 100 | V |
| Working peak reverse voltage | | V _{RWM} | 90 | 100 | V |
| Max. DC blocking voltage | | V _{DC} | 90 | 100 | V |
| Max. average forward rectified current at T_C = 133 °C | total device | levu e | 20 | | А |
| | per diode | I _{F(AV)} | 10 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 150 | | А |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs |
| Operating junction and storage temperature range | | TJ, T _{STG} | T _J , T _{STG} -65 to +150 | | °C |





COMPLIANT HALOGEN FREE



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| ELECTRICAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted) | | | | | | | |
|---|-----------------------|-------------------------|-------------------------------|-------|------|--|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | VALUE | UNIT | | |
| | I _F = 10 A | T _C = 25 °C | | 0.80 | | | |
| Max. instantaneous forward voltage per diode | $I_F = 10 A$ | T _C = 125 °C | V _F ⁽¹⁾ | 0.65 | V | | |
| | I _F = 20 A | $1_{\rm C} = 125$ C | | 0.75 | | | |
| Max. reverse current per diode at working peak reverse voltage | | T _J = 25 °C | I _R ⁽²⁾ | 100 | μA | | |
| | - | $T_J = 100 \ ^\circ C$ | | 6.0 | mA | | |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS | | | | | | |
|--------------------------------------|---------------------|-----------------------|------|--|--|--|
| PARAMETER | SYMBOL | MBR2090CT, MBR20100CT | UNIT | | | |
| Typical thermal resistance per diode | $R_{	heta JA}$ | 60 | °C/W | | | |
| | $R_{	ext{	heta}JC}$ | 2.0 | 0/10 | | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | MBR20100CT-M3/4W | 1.88 | 4W | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

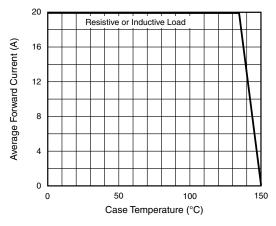


Fig. 1 - Forward Current Derating Curve

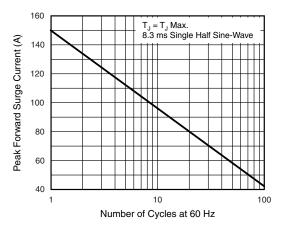


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode



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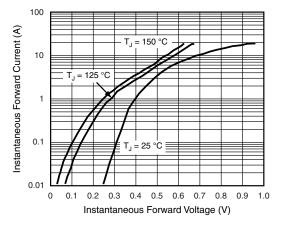


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

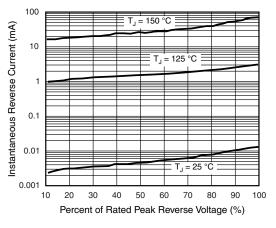


Fig. 4 - Typical Reverse Characteristics Per Diode

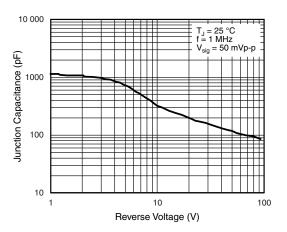


Fig. 5 - Typical Junction Capacitance Per Diode

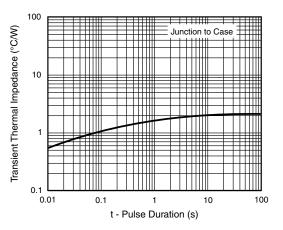
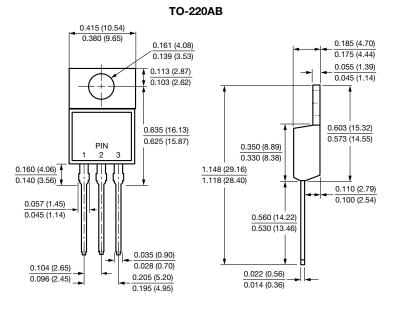


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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